

Graphene as an Enabler for Earth Observation

CEOI Technology Conference
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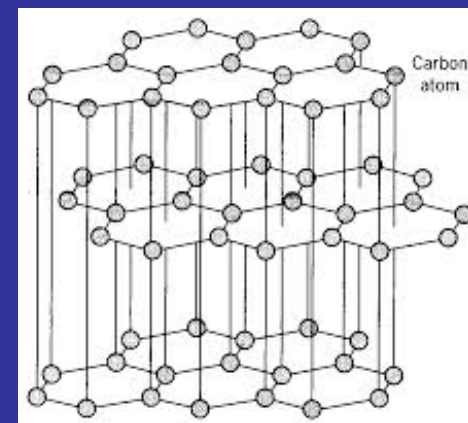
Jamie Williams MPhys
Postgraduate Research Student
jodw1@le.ac.uk

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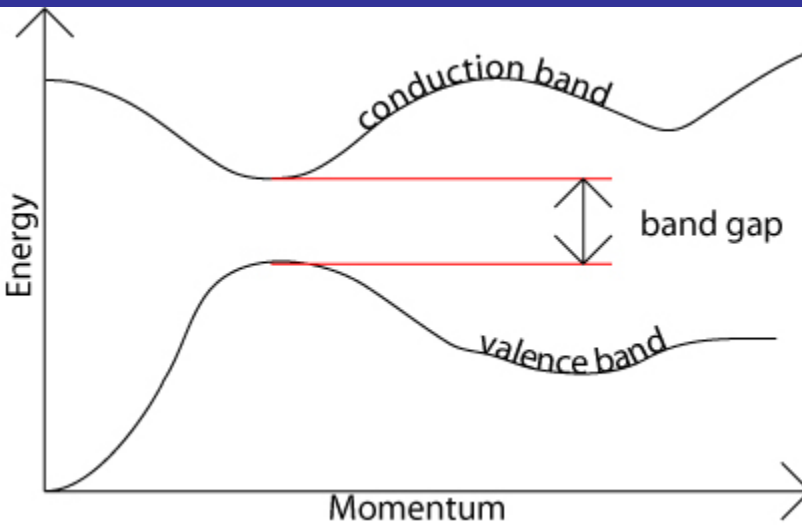
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- What is Graphene?
- Bilayer Graphene Single Photon Counting Photodetector
- Potential EO application(s) in the Optical
- Graphene Field Effect Transistor
- Potential EO application(s) in IR (& X-Ray)

Current Photodetector Technology

- Single Photon Counting Photodetectors:
 - Superconducting Tunnelling Junctions
 - Microwave Kinetic Inductance Detector
 - Transition Edge Sensor
 - Operation at sub-Kelvin temperatures requires He-3 cooling
- Higher energy photodetectors such as CZT, Scintillators etc

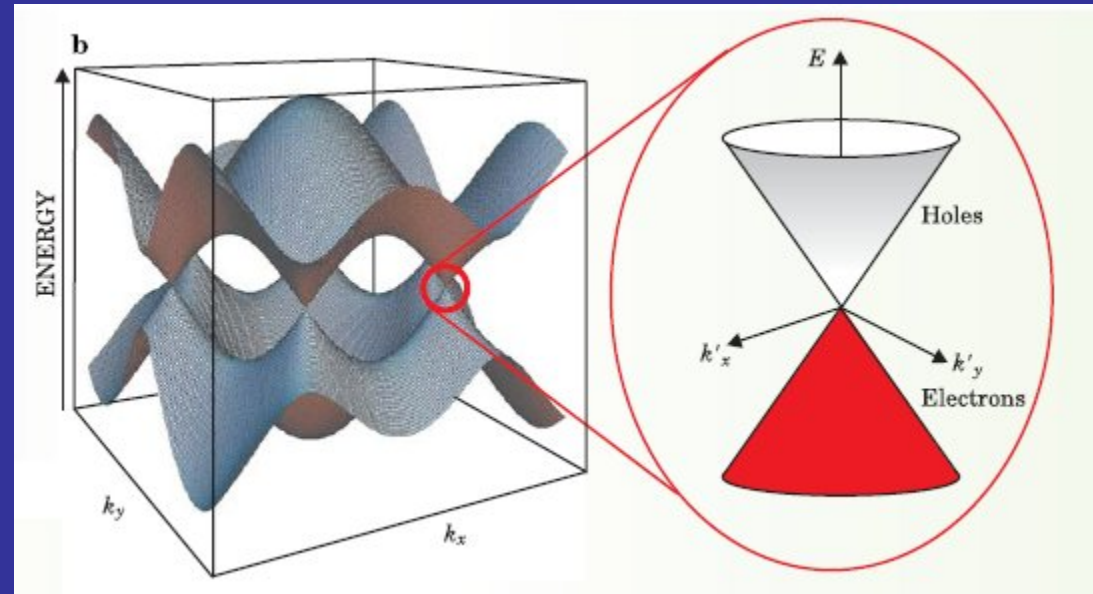


What is Graphene?



SILICON

University of Cambridge



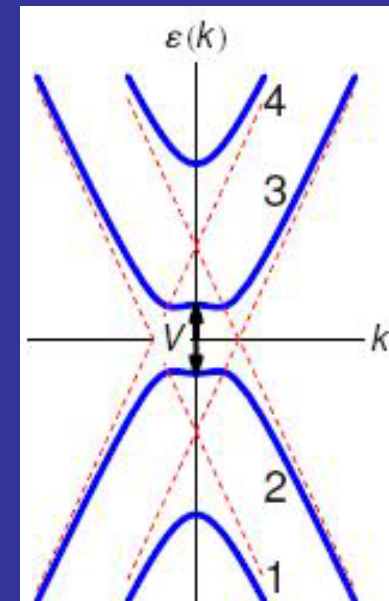
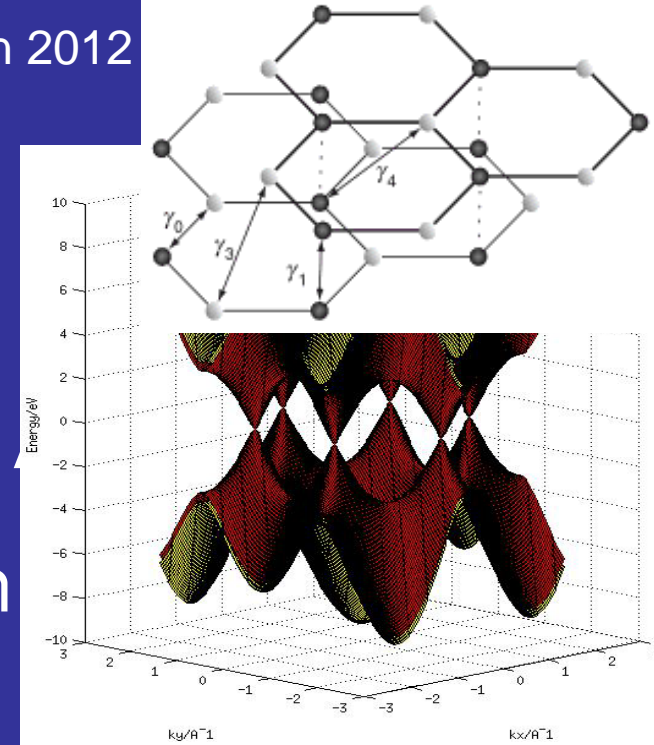
GRAPHENE

Graphenea

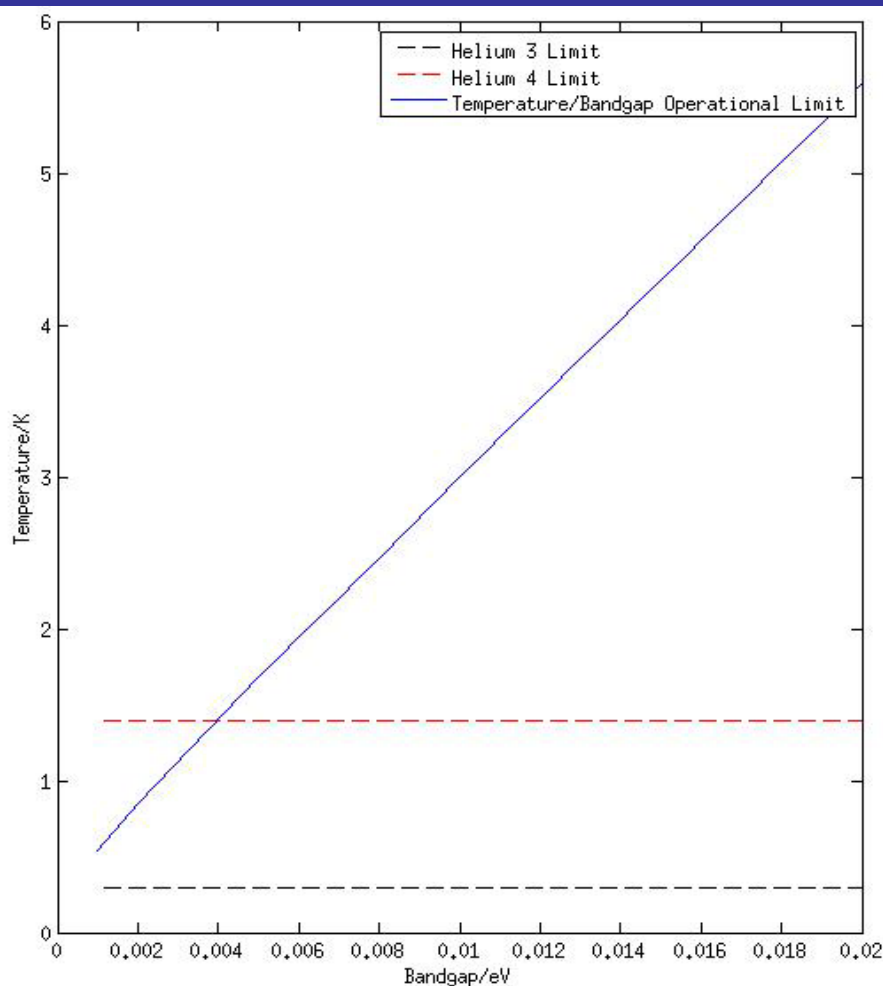
- Graphene is a “zero-bandgap-semiconductor”

What is Bilayer Graphene?

- Two layers of Carbon atoms in
- Naturally a "zero-bandgap-sem
- Tuneable band gap
 - Can be opened by electric field, doping, nanomodulation...
- Low energy terms \rightarrow trigonality
- Maintains mobility and absorption coefficient per layer



Bilayer Graphene Single Photon Counting Photodetector



- Density of states dependent on band gap and temperature → can deduce an operational limit
- Calculate the density of states and integrate over the F-D distribution to get the charge carrier density
- Look for $nA < 1$
- Obtain operational limit → Temperature–EG trade off

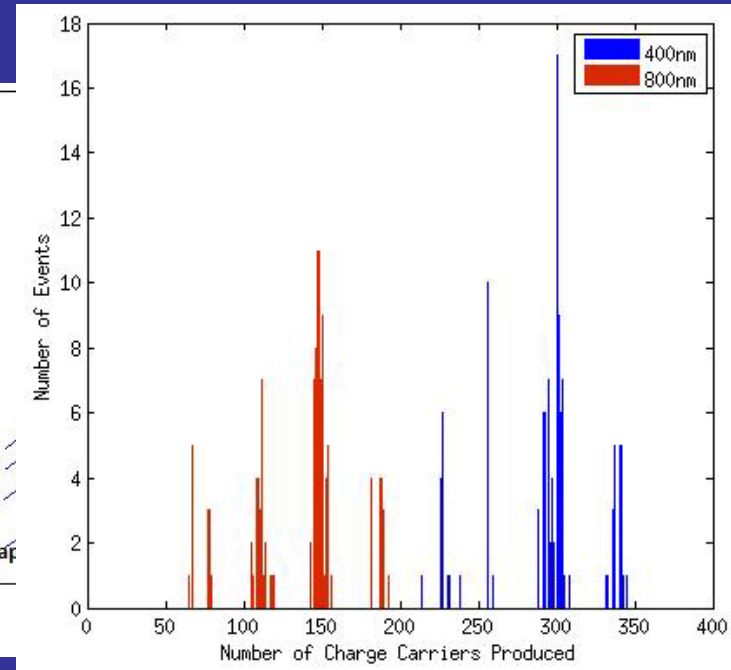
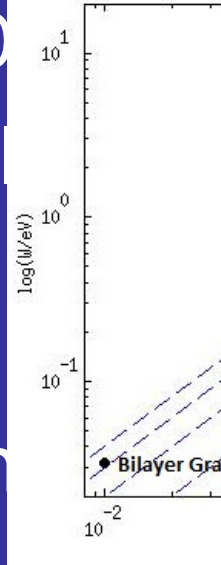
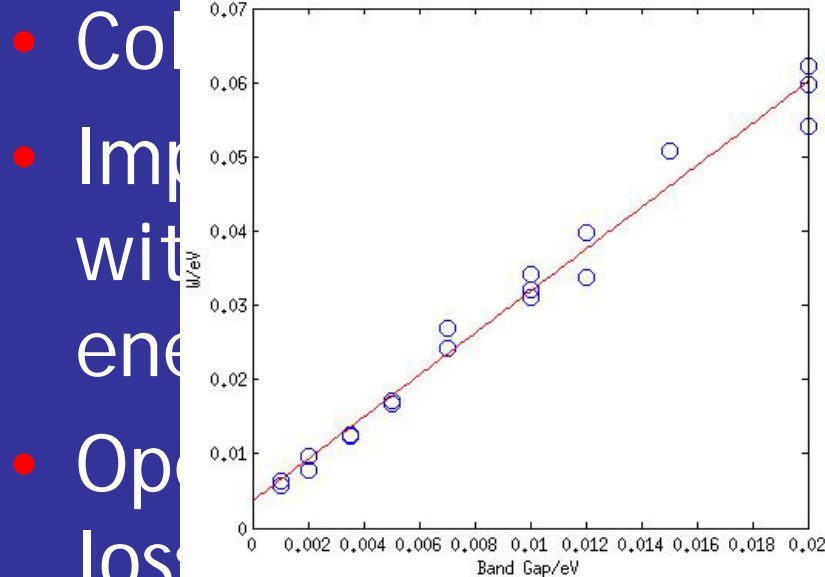
Bilayer Graphene Single Photon Counting Photodetector

- Design Requirements:-
 - Ultrafast detector – exploit very high mobility
 - Colour sensitivity in the visible spectrum
 - Be able to operate at higher temperatures with resolution trade off
 - Wide operating range → into IR as well?

Bilayer Graphene Single Photon Counting Photodetector

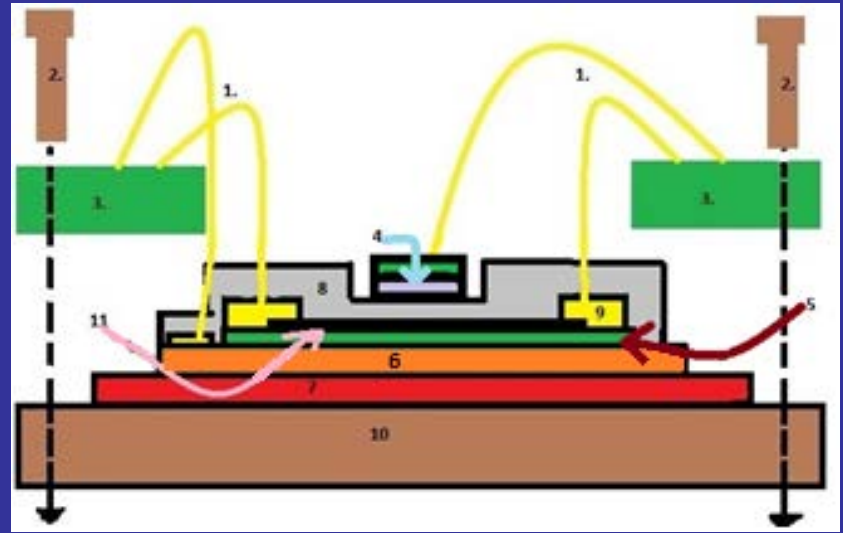
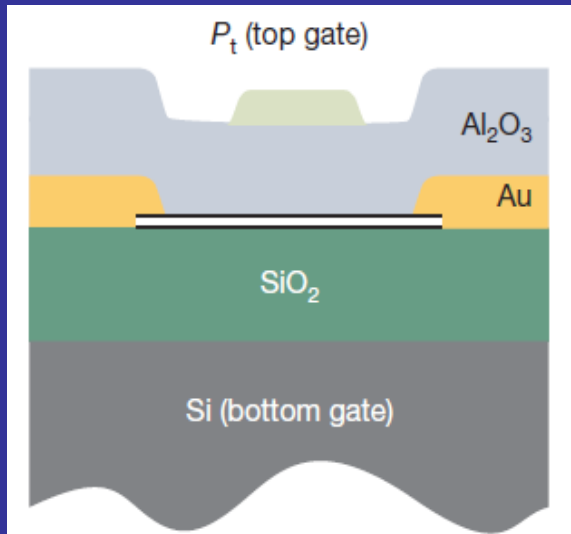
Results show:

- $W/E_G=3-4$ ratio similar to that of silicon and germanium



Bilayer Graphene Single Photon Counting Photodetector

- Initial prototype designs being manufactured by collaborators in Cambridge



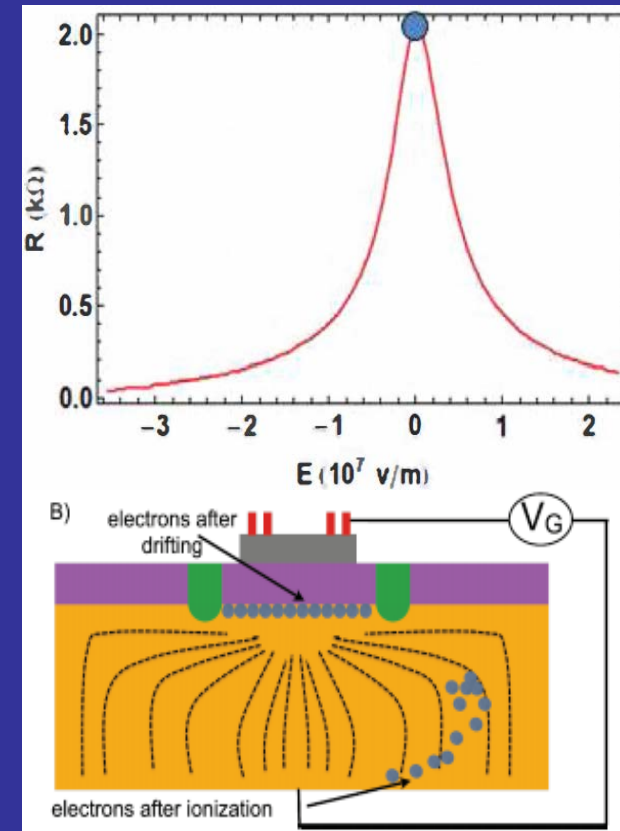
Potential EO application(s) in the Optical

- Applications would be able to operate at higher temperatures with band gap/temperature trade off
- Aerosol detection (MODIS, TOMS, OMI)
 - Single photon counter able to detect low intensity reflection peaks?
http://disc.sci.gsfc.nasa.gov/data-holdings/PIP/aerosol_index.shtml
 - Has colour sensitivity - identify the aerosol?
- Plankton Fluorescence
 - similar to Envisat?
 - able to detect different plankton?

Graphene Field Effect Transistor

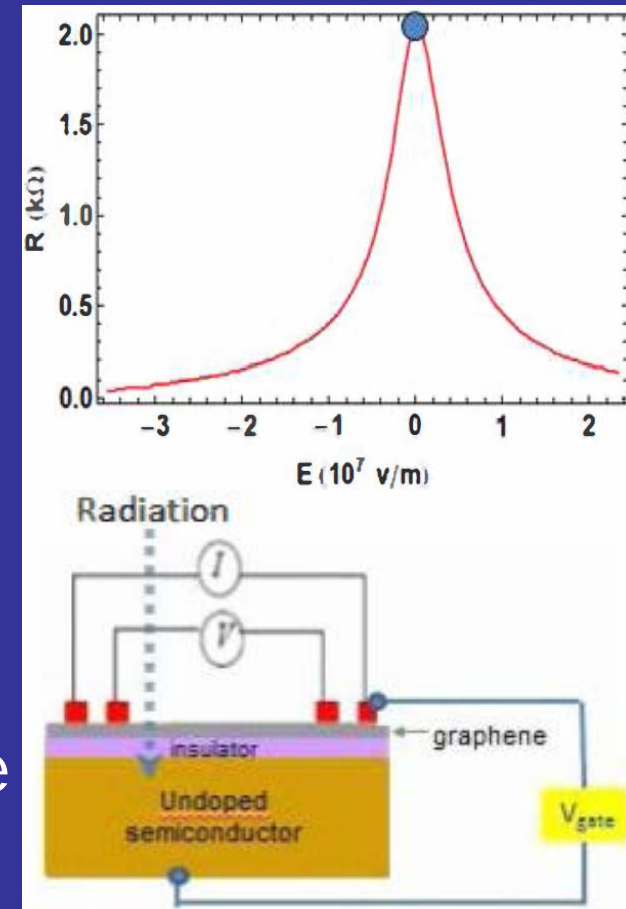
- Concept:-

- Exploits Field Effect in graphene
- Photon absorbed by Absorber material
- Resulting ionisation liberates electrons
- Gate voltage “funnels” electrons towards the buffer layer
- Field across the buffer applied to graphene changes resistivity
- Can resolve photon energy



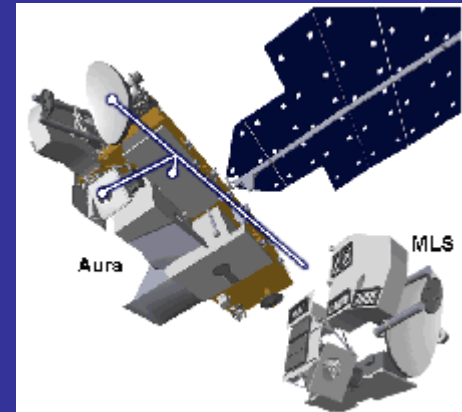
Graphene Field Effect Transistor

- Design Requirements:-
 - Prevent charge build up/saturation
 - shown in previous GFET devices
 - avoided in GDEPFET device → harder to manufacture
 - Return the Fermi level to the Dirac point as quickly as possible → more sensitive detection
 - Project began in March 2015 so no results to show...yet



Potential EO application(s) in IR & THz

- By clever design of the pixel layout, will have spatial sensitivity (as done by MKID)
- Microwave Limb Sounder
 - Measurements to understand the atmosphere through detection of thermal microwave emission from Earth's 'limb'
 - Use of graphene-based technology could allow for quicker, more sensitive detection and higher temperature with optimisation of absorber
- Radiometry
 - Issues with saturation on ASTER SWIR could be avoided



<http://mls.jpl.nasa.gov/index-eos-mls.php>

Conclusions

- Many opportunities for graphene-based technologies in Earth observation
- BLG detector able to count single photons, operating at higher temperature with colour sensitivity
- GFET to have improved energy resolution
- They would have spatial and energy sensitivity
- Aim is for a working 1-pixel BLG detector prototype by end of 2015.

References and Acknowledgements

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Department of Physics and Astronomy, University of Leicester

- Jon Lapington, Ian Hutchinson, Mervyn Roy, Gauthier Torricelli and George Fraser

Cambridge Graphene Centre, University of Cambridge

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